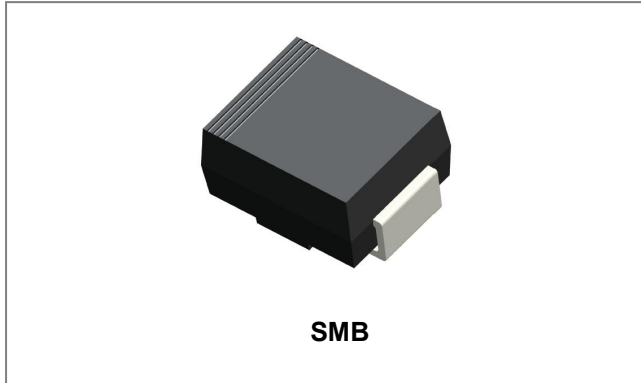


ER2M ULTRAFAST RECTIFIER



Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Overload Drop, High Efficiency
- Low Power Loss
- Super-Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- Terminals finish: Tin Lead-free plated
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: Low Profile Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.09grams(approx)

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic	Symbol	ER2M	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	1000	V
Working Peak Reverse Voltage	V _{RWM}		
DC Blocking Voltage	V _R		
RMS Reverse Voltage	V _{R(RMS)}	700	V
Average Rectified Output Current @T _A = 75°C	I _O	2.0	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	50.0	A
Forward Voltage @I _F = 2.0A, T _J =25°C	V _F	1.7	V
Peak Reverse Current @T _A = 25°C	I _{RM}	5.0	μA
At Rated DC Blocking Voltage @T _A = 100°C		50.0	
Typical Thermal Resistance Junction to Ambient (Note 1)	R _{θJA}	40	°C/W
Maximum Reverse Recovery Time (Note 2)	T _{rr}	75	ns
Typical Junction Capacitance (Note 3)	C _J	60	pF
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Note: 1. Mounted on P.C. Board with 8.0mm² lead area
 2. Measured with I_F=0.5A, I_R=1.0A, I_{rr}=0.25A,
 3. Measured at 1.0 MHz and applied reverse voltage of 4.0 V_{DC}

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Ratings and Characteristics Curves

FIG. 1- FORWARD CURRENT DERATING CURVE

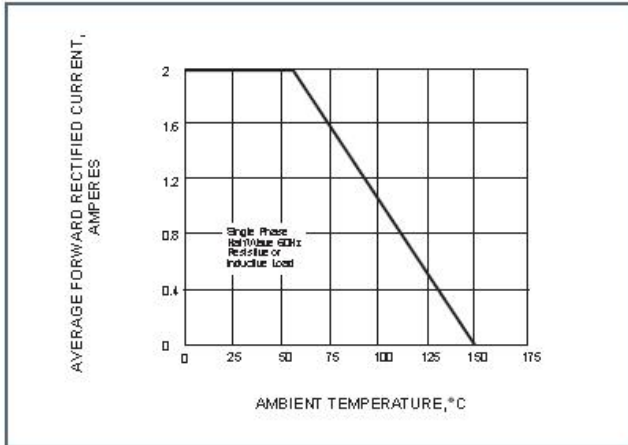


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

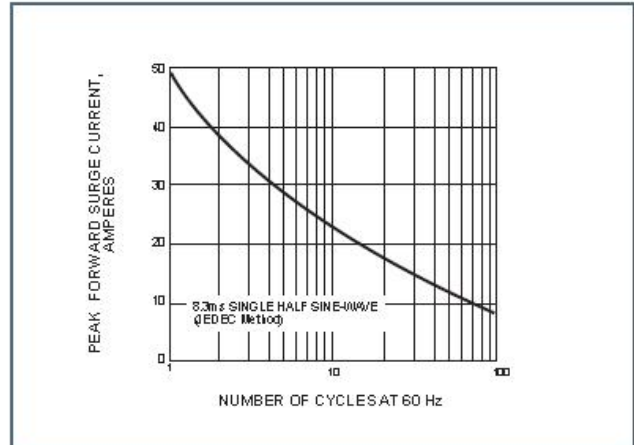


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

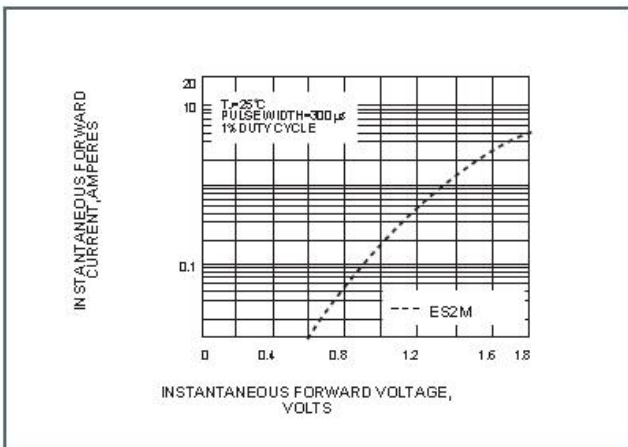
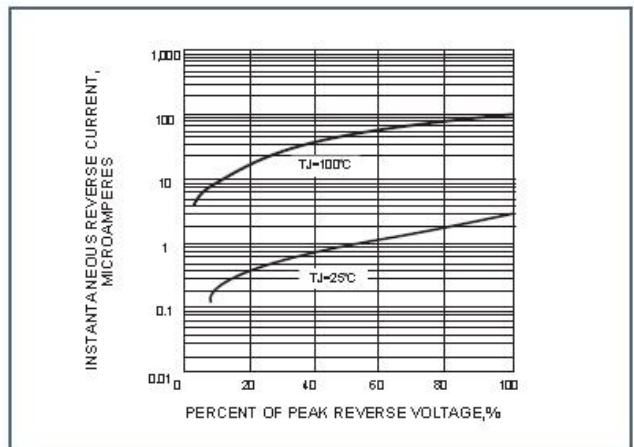
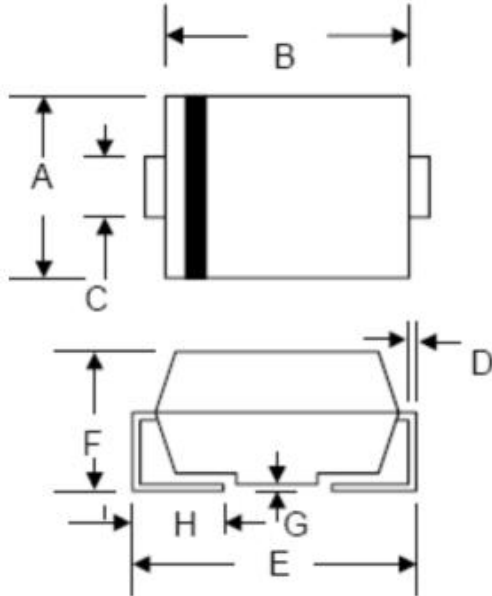


FIG. 4-TYPICAL REVERSE CHARACTERISTICS



Mechanical Dimensions SMB


SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	3.30	3.94	0.130	0.155
B	4.06	4.70	0.160	0.185
C	1.80	2.20	0.071	0.087
D	0.152	0.305	0.006	0.012
E	4.80	5.59	0.189	0.220
F	2.10	2.60	0.083	0.102
G	0.051	0.203	0.002	0.008
H	0.76	1.52	0.030	0.060

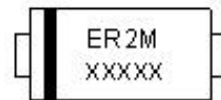
Ordering Information

Device	Package	Shipping
ER2M	SMB (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

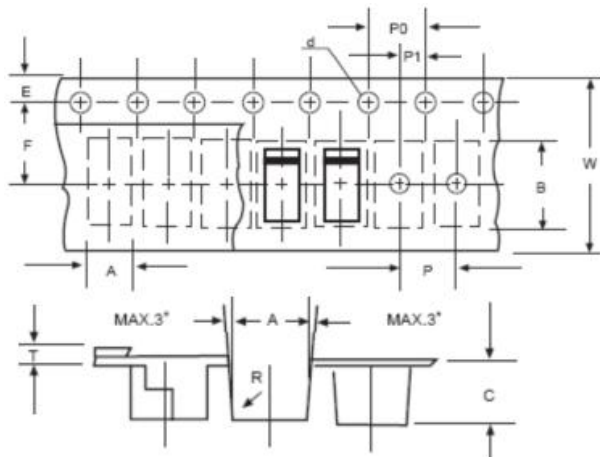
Marking Diagram

Where XXXXX is YYWWL



ER = Device Type
 2 = Forward Current (2A)
 M = Reverse Voltage (1000V)
 YY = Year
 WW = Week
 L = Lot Number

Cautions: Molding resin
 Epoxy resin UL:94V-0

Carrier Tape Specification SMB


SYMBOL	Millimeters	
	Min.	Max.
A	2.97	3.17
B	5.70	5.90
C	2.32	2.52
d	1.40	1.60
E	1.40	1.60
F	5.60	5.70
P	3.90	4.10
P0	3.90	4.10
P1	1.90	2.10
T	0.25	0.35
W	11.80	12.20

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